

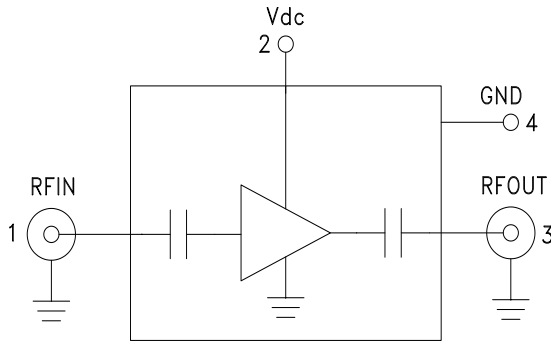


Typical Applications

The HMC-C050 is ideal for:

- Microwave Radio
- Military & Space
- Test Instrumentation
- VSAT

Functional Diagram



Features

- Ultra Low Phase Noise: -160 dBc/Hz @ 10 kHz
- Noise Figure: 5 dB
- Gain: 13.5 dB
- Output IP3: +22.5 dBm
- 50 Ohm Matched Input/Output
- Single Supply Voltage: +5V
- Hermetically Sealed Module
- Field Replaceable SMA Connectors
- 55 °C to +85 °C Operating Temperature

General Description

The HMC-C050 is a GaAs HBT Ultra Low Noise Amplifier in a miniature, hermetic module designed to operate between 2 and 18 GHz. This high dynamic range amplifier module provides 13.5 dB of gain, 5 dB noise figure and up to +22.5 dBm of OIP3 with a single supply of +5V. The ultra low phase noise contribution of -160 dBc/Hz, enables superior modulation accuracy within transceiver architectures. The wideband distributed amplifier I/O's are internally matched to 50 Ohms and DC blocked for robust performance. The module features removable SMA connectors which can be detached to allow direct connection of the I/O pins to a microstrip or coplanar circuit.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{dc} = +5\text{V}$

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	8 - 12.5			2 - 18			GHz
Gain	10.5	13.5		9.5	12.5		dB
Gain Flatness		± 1.2			± 2.2		dB
Gain Variation Over Temperature		0.021			0.027		dB/ °C
Noise Figure		4.5			6.5		dB
Input Return Loss		18			16		dB
Output Return Loss		17			15		dB
Output Power for 1 dB Compression (P1dB)	13	15		8	13		dBm
Saturated Output Power (Psat)		18.5			16		dBm
Output Third Order Intercept (IP3)		22.5			20		dBm
Phase Noise @ 100 Hz		-140			-150		dBc/Hz
Phase Noise @ 1 kHz		-150			-150		dBc/Hz
Phase Noise @ 10 kHz		-160			-150		dBc/Hz
Phase Noise @ 1 MHz		-165			-160		dBc/Hz
Supply Current		80	104		80	104	mA

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HMC-C050* PRODUCT PAGE QUICK LINKS

Last Content Update: 11/29/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

DOCUMENTATION

Data Sheet

- HMC-C050 Data Sheet

TOOLS AND SIMULATIONS

- HMC-C050 S-Parameter

DESIGN RESOURCES

- HMC-C050 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC-C050 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK

Submit feedback for this data sheet.

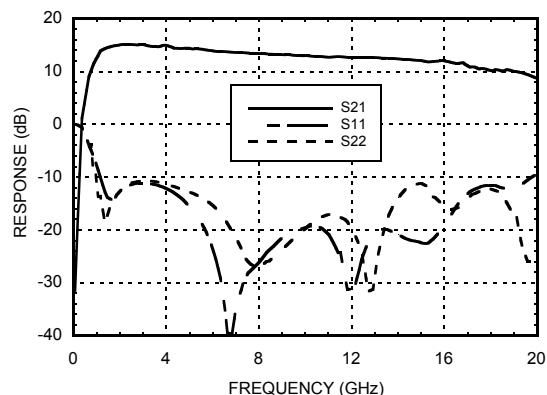


**ULTRA LOW PHASE NOISE
DISTRIBUTED AMPLIFIER, 2 - 18 GHz**

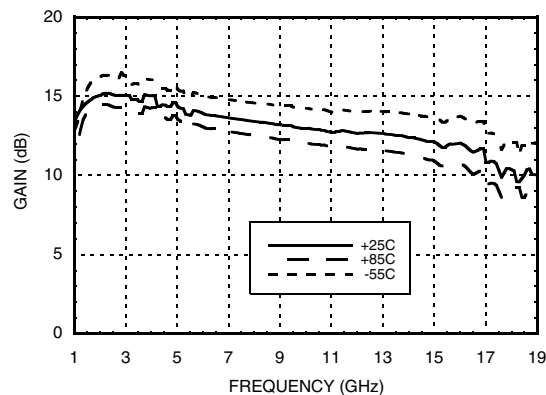
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AMPLIFIERS

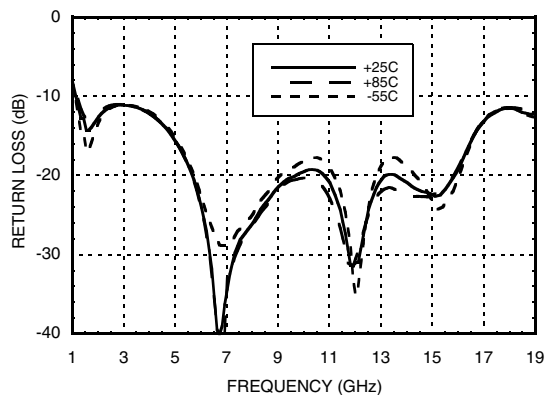
Gain & Return Loss



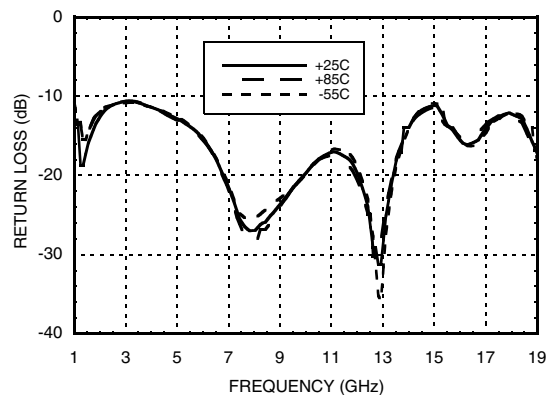
Gain vs. Temperature



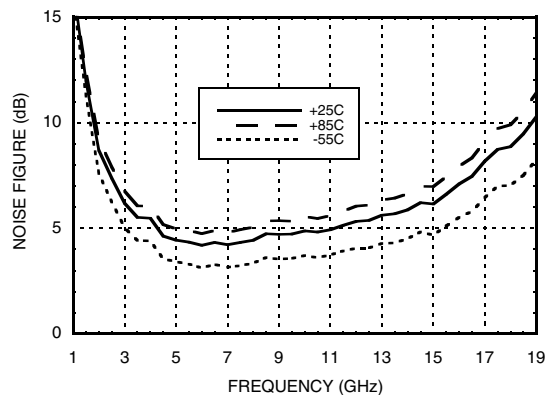
Input Return Loss vs. Temperature



Output Return Loss vs. Temperature

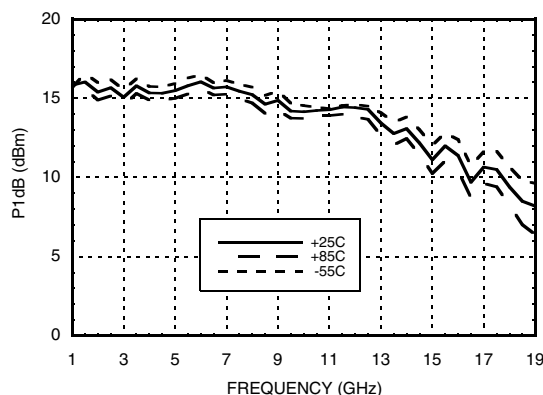
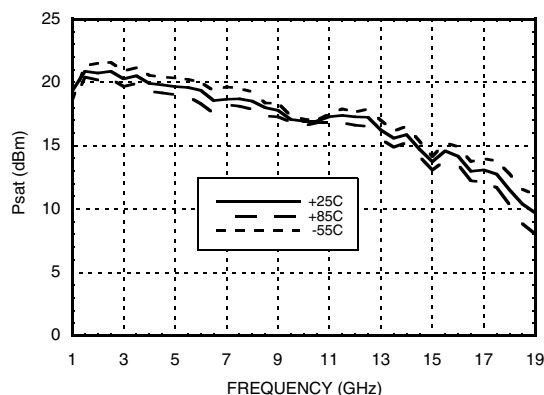
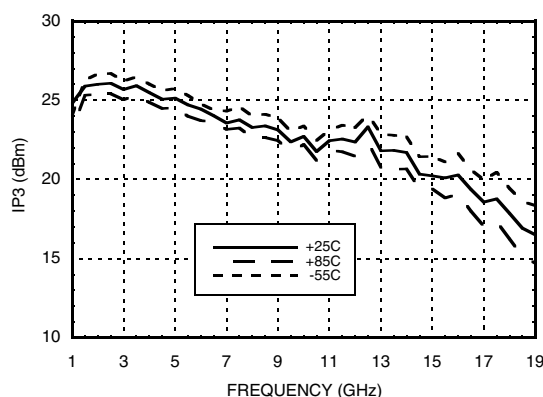
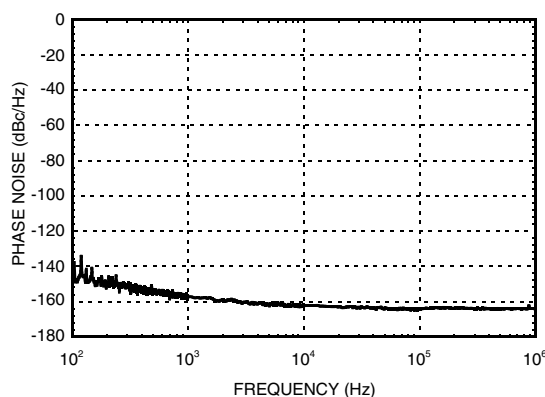
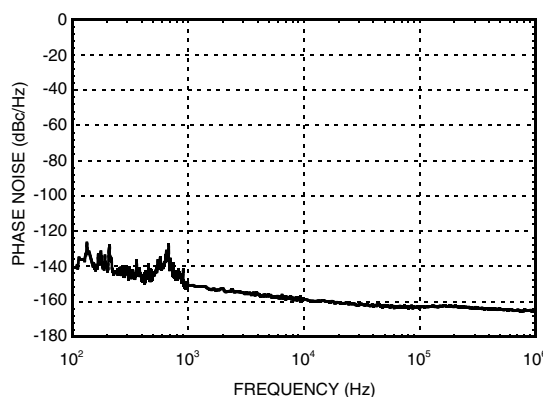
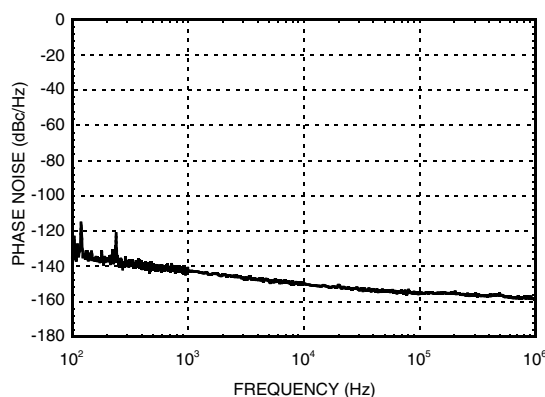


Noise Figure vs. Temperature





ULTRA LOW PHASE NOISE DISTRIBUTED AMPLIFIER, 2 - 18 GHz

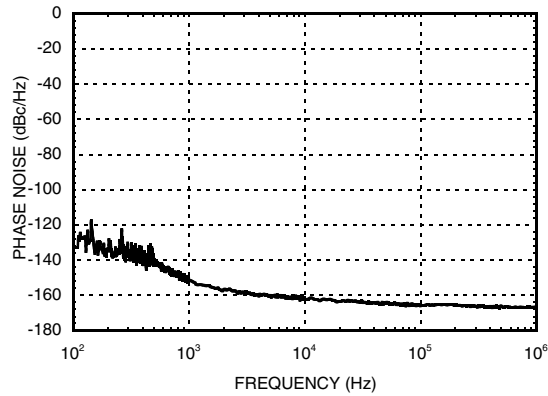
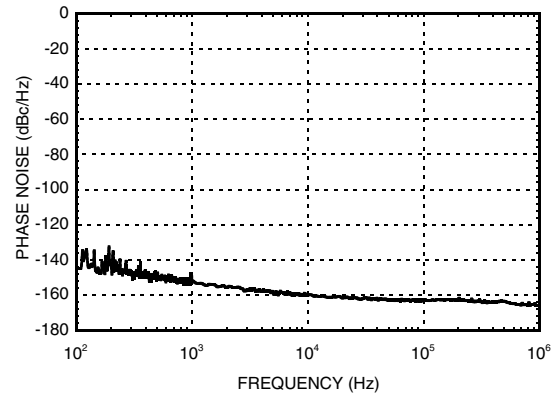
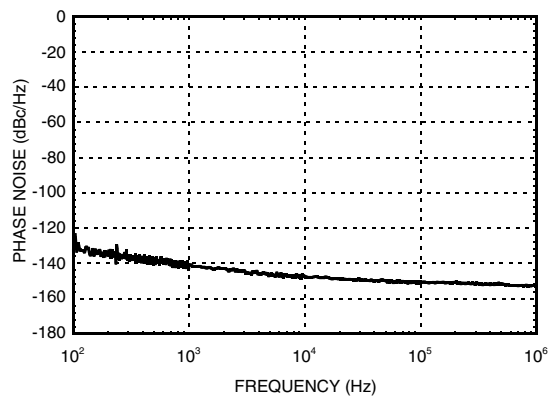
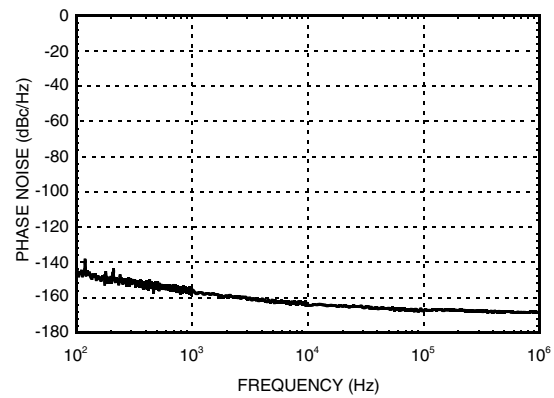
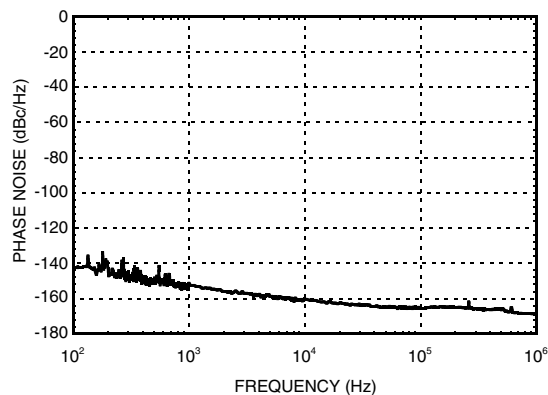
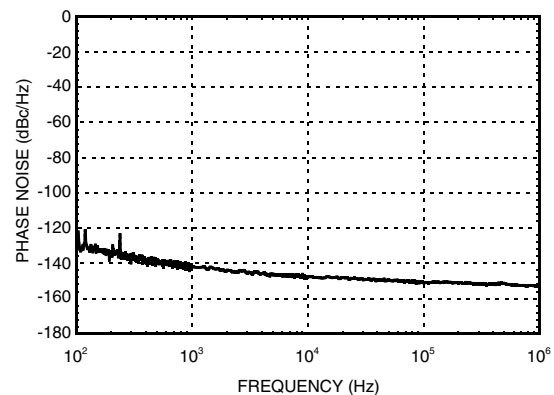
P1dB vs. Temperature

Psat vs. Temperature

Output IP3 vs. Temperature

Phase Noise at Pout = 0 dBm @ 2 GHz

Phase Noise at Pout = 0 dBm @ 12 GHz

Phase Noise at Pout = 0 dBm @ 18 GHz




ULTRA LOW PHASE NOISE DISTRIBUTED AMPLIFIER, 2 - 18 GHz

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AMPLIFIERS

Phase Noise at Psat @ 2 GHz

Phase Noise at Psat @ 12 GHz

Phase Noise at Psat @ 18 GHz

Phase Noise at P1dB @ 2 GHz

Phase Noise at P1dB @ 12 GHz

Phase Noise at P1dB @ 18 GHz




ULTRA LOW PHASE NOISE DISTRIBUTED AMPLIFIER, 2 - 18 GHz

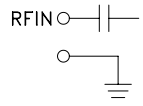

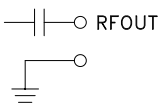
Absolute Maximum Ratings

Bias Supply Voltage (Vdc)	+7V
RF Input Power (RFIN)	+15 dBm
Continuous P _{diss} (T = 85 °C)	0.65W
Channel Temperature	175 °C
Thermal Resistance	91.5 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	RFIN & RF Ground	RF input connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	
2	Vdc	Power supply voltage for the amplifier.	
3	RFOUT & RF Ground	RF output connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	
4	GND	Power supply ground.	